



MSB25MH(LS)

GLASS PASSIVATED SUFACE MOUNT BRIDGE RECTIFIER

REVERSE VOLTAGE - 1000 Volts FORWARD CURRENT - 2.5 Amperes

GENERAL DESCRIPTION

Suitable for AC-to-DC bridge full wave rectification for SMPS, LED lighting, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

FEATURES

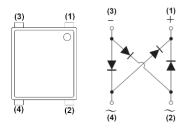
- Rating to 1000V PRV
- · Ideal for SMT manufacturing
- · Compact, thin profile package design
- · Reliable robust construction
- UL recognized file #E364304
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

MECHANICAL DATA

- · Package Material: Green molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl.)
- · Polarity indicator: Symbol molded on body
- Weight: 216mg (Approximate)



Pin Assignment



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

MAXIMIM RATINGS @ T₄ = 25°C unless otherwise specified

PARAMETER		SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	1000	V
Maximum DC blocking voltage		V _{DC}	1000	V
Average rectified output current per device	T _C = 110°C	I _(AV)	2.5	Α
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	T _J = 25°C T _J = 125°C	I _{FSM}	80 64	А
Peak forward surge current 1ms single half sine-wave superimposed on rated load	T _J = 25°C T _J = 125°C	I _{FSM}	160 128	А
I^2 t rating for fusing (t = 8.3ms)		l ² t	26.5	A ² s
Operating and storage temperature range		T _J , T _{STG}	-55 to +150	°C

STATIC ELECTRICAL CHARACTERISTICS

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PARAMETER	TEST CONDITION		SYMBOL	TYP	MAX	UNIT	
Forward voltage	I _F = 1.25A	T _J = 25°C T _J = 125°C	V _F	 0.78	1.02 	\/	
Forward voltage	I _F = 2.5A	T _J = 25°C T _J = 125°C	VF	 0.86	1.1 	V	
Leakage current	V _R = 1000V	$T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$	I _R	-1	5 500	uA	
Typical junction capacitance (Note 4)			Ст	3	60	pF	

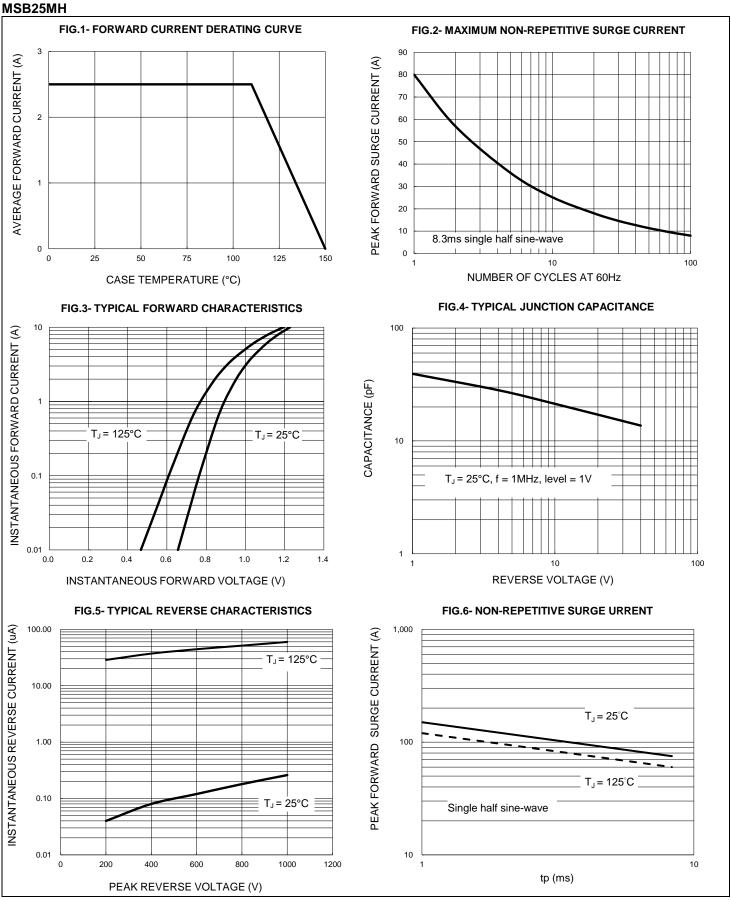
THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	VALUE	UNIT
	$RthJ_A$	35	
Typical thermal resistance (Note 5)	RthJ _c	7.8	°C/W
	RthJ∟	16	

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 5. Thermal resistance test performed in accordance with JESD-51. Unit mounted on glass-epoxy substrate with 1oz/ft2_30mm x 30mm copper pad per pin.



RATING AND CHARACTERISTIC CURVES

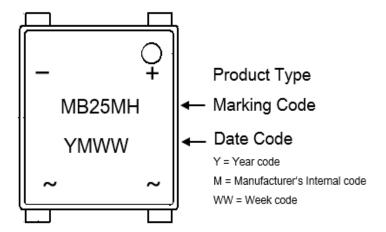




Ordering Information:

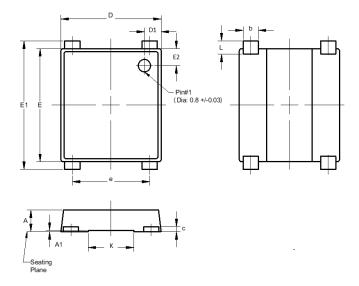
Part Number	Package	Packing		
Fait Nullibei	Fackage	Qty.	Carrier	
MSB25MH_HF	MSBL	2500pcs	Tape & Reel	

Marking Information:



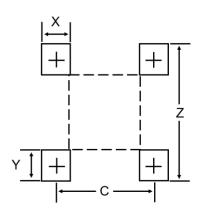


Package Dimensions:



	MSBL				
Dim	Min Max				
Α	1.30	1.50			
A1	0.04	0.08			
C	0.27	0.40			
D	6.50	6.70			
D1	0.95	1.25			
Е	7.20	7.40			
E1	7.90	8.60			
E2	0.95	1.25			
١	0.65	1.05			
b	0.95	1.15			
е	5.00 5.20				
K	2.90	3.10			
All Dimensions in mm					

Suggested Pad Layout:



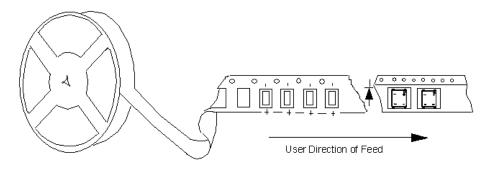
Dimensions	Value (in mm)
С	5.40
X	2.00
Y	2.50
Z	10.71



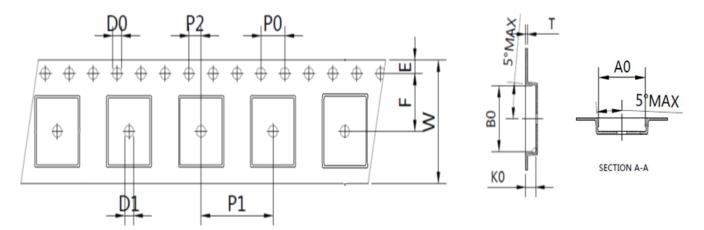
Packaging Information:

Package	Qty./Reel (Pcs)	Reel Dia. (mm)	Carton Size (mm)	Qty./Carton MOQ (Pcs)
MSBL	2500	330	355*345*245	25k

Polar Units



Embossed Carrier Dimensions:



Unit: mm

DIM.	A0	В0	K0	P0	P1	P2
SPEC	7.00±0.10	8.85±0.10	1.70±0.10	4.00±0.10	12.0±0.10	2.00±0.10
DIM.	Т	E	F	D0	D1	W
SPEC	0.30±0.05	1.75±0.10	7.50±0.10	1.50±0.1	1.50(min)	16.00±0.30

Remark: 10 Sprocket hole pitch cumulative tolerance is ±0.20mm



Typical IR Reflow Soldering Thermal Profile:

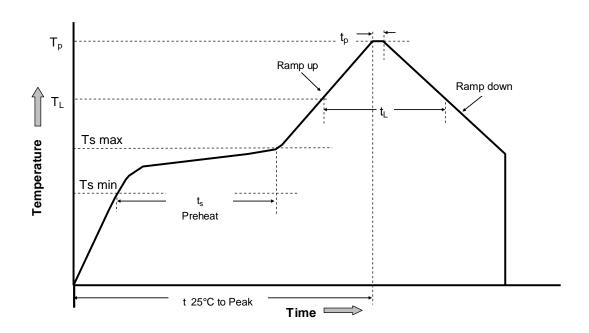


Table 1- Reflow profile

Table 1- Nellow profile						
Reflow condition	Sn-Pb assembly	Pb-free assembly				
Average ramp-up rate (Liquidus Temperautre (TL) to Peak)	3 °C/second max.	3 °C/second max.				
Preheat						
Tempautre Min, Ts (Min)	100 °C	150 °C				
Temperature Max, Ts (Max)	150 °C	200 °C				
Time (min to max, ts)	60-120 seconds	60-180 seconds				
Ts(max) to TL		3 °C/second max.				
- Ramp-up Rate		5 C/Second max.				
Time maintained above:						
Temperature(TL)	183 °C	217 °C				
Time(tL)	60-150 seconds	60-150 seconds				
Peak Temperature (Tp)	240 +0/-5 °C	260 +0/-5 °C				
Time within 5 °C of actual Peak	10-30 seconds	20-40 seconds				
Temperature(tp)	10-30 36001103	20-40 Seconds				
Ramp-down Rate	6 °C/second max.	6 °C/second max.				
Time 25 °C to Peak Temperature.	6 minutes max.	8 minutes max.				

Note: All temperatures refer to topside of the package, measured on the package body surface



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